

## Load Switch with Level-Shift

### UM3865P SOT363

#### General Description

The UM3865P includes a p- and n-channel MOSFET in a single SOT363 package. The low on-resistance p-channel MOSFET is tailored for use as a load switch. The n-channel, with an external resistor, can be used as a level-shift to drive the p-channel load switch. The n-channel MOSFET has internal ESD protection and can be driven by logic signals as low as 1.5V. The UM3865P operates on supply lines from 1.8V to 8V, and can drive loads up to 1A.

#### Applications

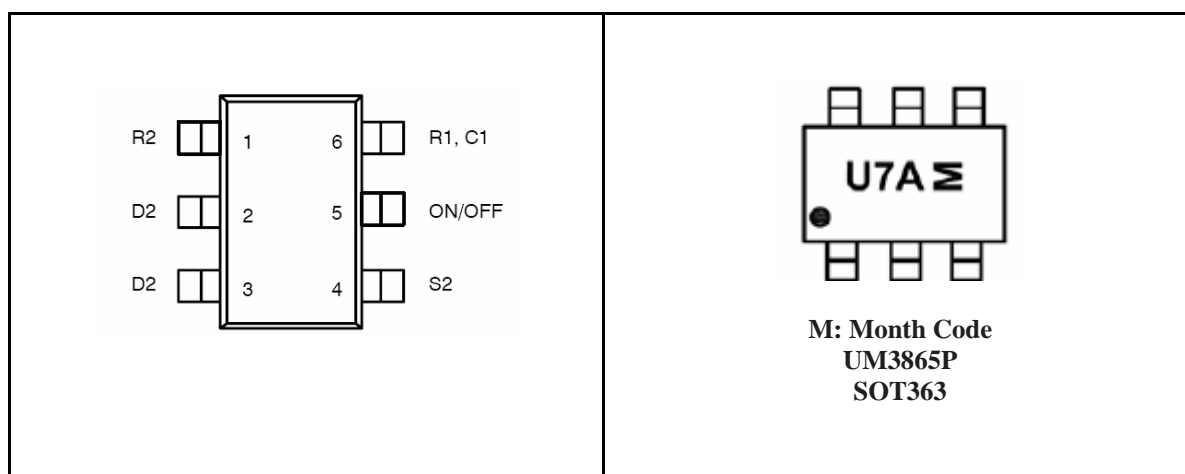
- Battery Packs
- Battery-powered Portable Equipment
- Cellular and Cordless Telephones

#### Features

- 300 mΩ Low On-Resistance
- 1.8V to 8V Input
- 1.5V to 8V Logic Level Control
- Low Profile, Small Footprint SOT363 Package
- 2000V ESD Protection On Input Switch
- Adjustable Slew-Rate

#### Pin Configurations

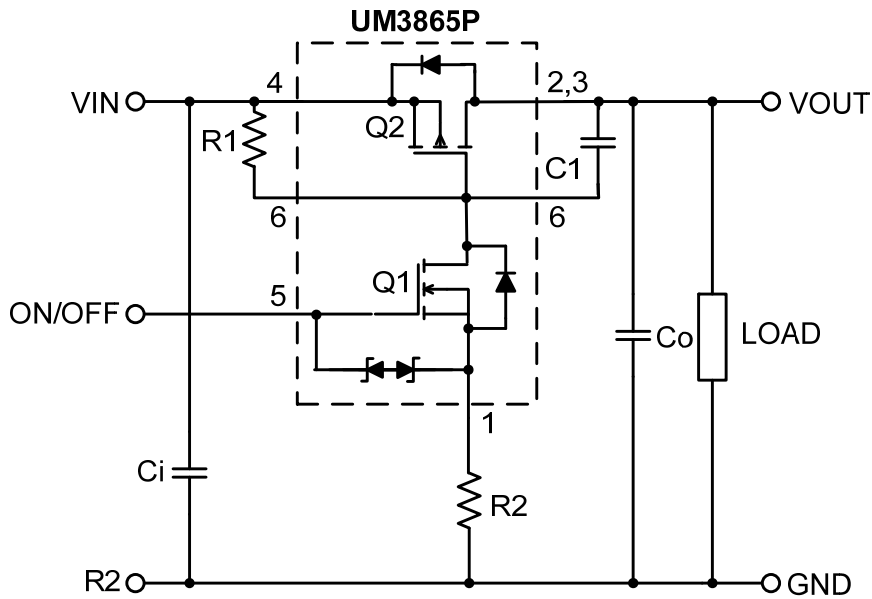
#### Top View



#### Ordering Information

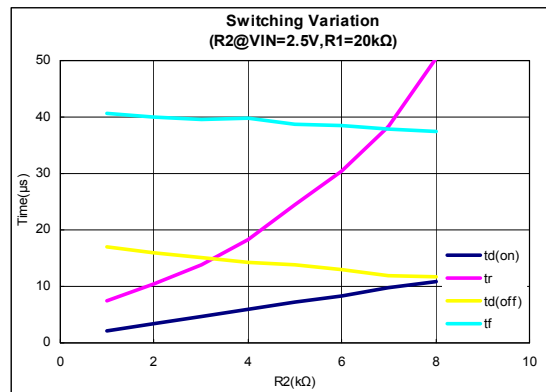
Part Number	Packaging Type	Marking Code	Shipping Qty
UM3865P	SOT363	U7A	3000pcs/7 Inch Tape & Reel

## Typical Application Circuit



COMPONENTS		
R1	Pull-Up Resistor	Typical 20kΩ to 1MΩ*
R2	Optional Slew-Rate Control	Typical 0 to 50kΩ
C1	Optional Slew-Rate Control	Typical 1000pF

\*Minimum R1 value should be at least  $10 \times R2$  to ensure Q1 turn-on.



Note: For R2 switching variations with other VIN/R1 combinations See Typical Characteristics

**Absolute Maximum Ratings**

Symbol	Parameter	Limit	Unit
$V_{IN}$	Input Voltage	8	V
$V_{ON/OFF}$	ON/OFF Voltage	8	
$I_L$	Continuous Load Current <sup>(1)(2)</sup>	±1	A
	Pulse Load Current <sup>(2)(3)</sup>	±5	
$I_S$	Continuous Source Current (Source-Drain Diode)	-1.0	
$P_D$	Maximum Power Dissipation	0.5	W
$T_J, T_{STG}$	Junction and Storage Temperature Range	- 50 to +150	°C
ESD	ESD Rating, MIL-STD-883D HBM	2000	V
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	250	°C/W

**Electrical Characteristics ( $T_J=25^\circ\text{C}$ , Unless Otherwise Noted)**

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
<b>OFF Characteristics</b>						
$I_{FL}$	Reverse Leakage Current	$V_{IN}=8\text{V}, V_{ON/OFF}=0\text{V}$			1	μA
$V_{SD}$	Diode Forward Voltage	$I_S = -1\text{ A}$		-0.73	-1	V
<b>ON Characteristics</b>						
$V_{IN}$	Input Voltage Range		1.8		8	V
$R_{DS(ON)}$	Static Drain-to-Source On-Resistance	$V_{ON/OFF}=1.5\text{V}, V_{IN}=4.5\text{V}, I_D=1.0\text{A}$		0.300	0.350	Ω
		$V_{ON/OFF}=1.5\text{V}, V_{IN}=2.5\text{V}, I_D=1.0\text{A}$		0.400	0.450	
$I_{D(on)}$	On-State (p-channel) Drain Current	$V_{IN-OUT} \leq 0.2\text{V}, V_{IN}=5\text{V}, V_{ON/OFF}=1.5\text{V}$	0.7			A
		$V_{IN-OUT} \leq 0.3\text{V}, V_{IN}=3\text{V}, V_{ON/OFF}=1.5\text{V}$	0.8			

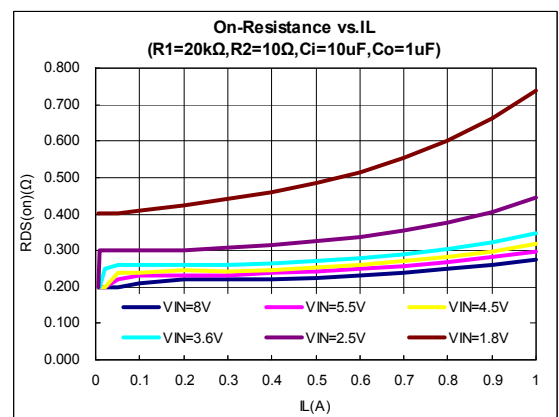
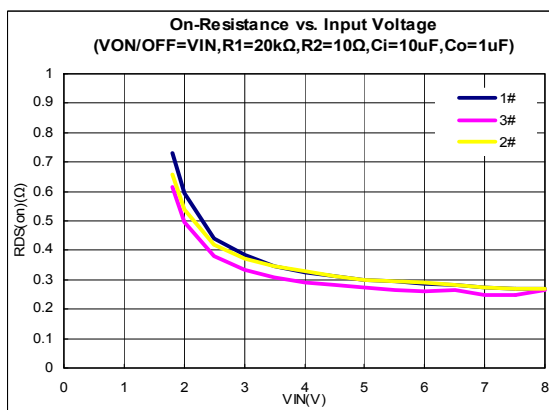
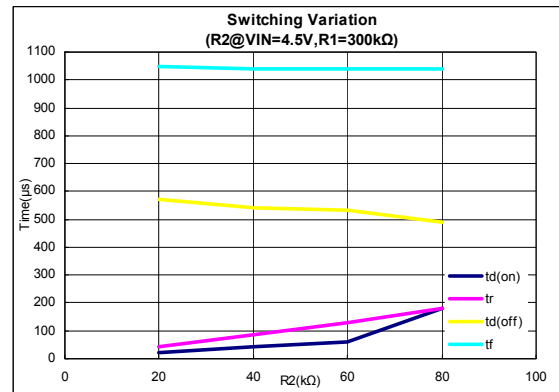
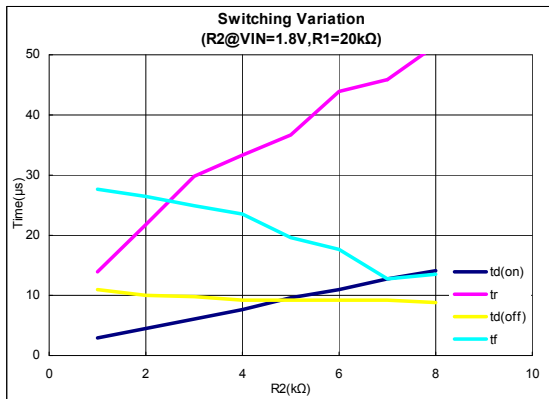
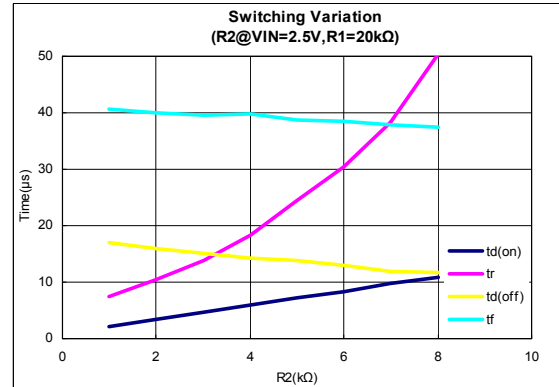
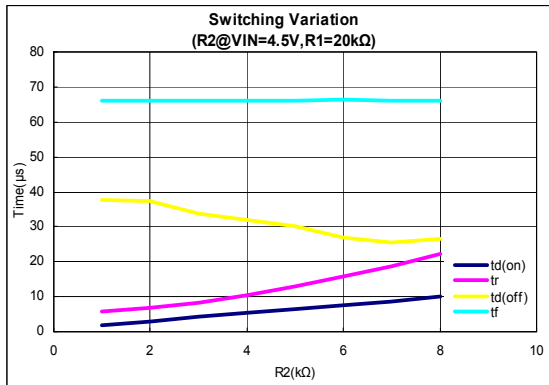
Notes:

(1): Surface Mounted on FR4 Board

 (2):  $V_{IN}=8\text{V}, V_{ON/OFF}=8\text{V}, T_A=25^\circ\text{C}$ 

 (3): Pulse test: Pulse Width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$

## Typical Characteristics ( $T_J=25^\circ\text{C}$ , Unless Otherwise Noted)



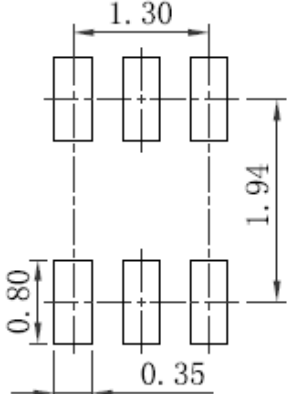
## Package Information

### UM3865P SOT363

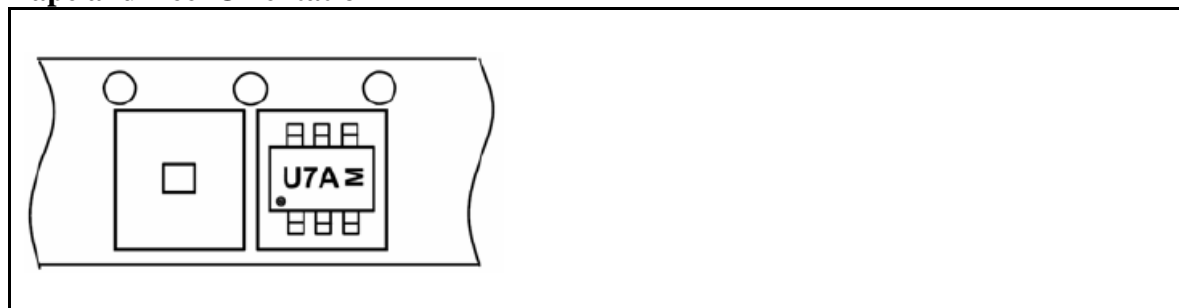
#### Outline Drawing

DIMENSIONS				
Symbol	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.036	0.039
b	0.100	0.350	0.004	0.014
c	0.080	0.220	0.003	0.009
D	1.800	2.200	0.071	0.087
E	1.150	1.350	0.045	0.053
E1	2.000	2.450	0.079	0.096
e	0.650REF		0.026REF	
e1	1.200	1.400	0.047	0.055
L	0.525REF		0.021REF	
L1	0.260	0.460	0.010	0.018
$\theta$	0°	8°	0°	8°

#### Land Pattern

	<p>NOTES:</p> <ol style="list-style-type: none"> <li>Compound dimension: 2.10×1.25;</li> <li>Unit: mm;</li> <li>General tolerance ±0.05mm unless otherwise specified;</li> <li>The layout is just for reference.</li> </ol>
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#### Tape and Reel Orientation



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